Low-Voltage 1.8/2.5/3.3V 16-Bit D-Type Flip-Flop With 26Ω Series Resisters and 3.6V–Tolerant Inputs and Outputs (3–State, Non–Inverting)

The 74VCX162374 is an advanced performance, non-inverting 16-bit D-type flip-flop. It is designed for very high-speed, very low-power operation in 1.8 V, 2.5 V or 3.3 V systems. The VCX162374 is byte controlled, with each byte functioning identically, but independently. Each byte has separate Output Enable and Clock Pulse inputs. These control pins can be tied together for full 16-bit operation.

When operating at 2.5 V (or 1.8 V) the part is designed to tolerate voltages it may encounter on either inputs or outputs when interfacing to 3.3 V busses. It is guaranteed to be over–voltage tolerant to 3.6 V.

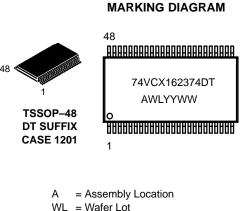
The 74VCX162374 consists of 16 edge–triggered flip–flops with individual D–type inputs and 3.6 V–tolerant 3–state outputs. It is designed with 26 Ω series resistors in each of the outputs to reduce noise. The clocks (CPn) and Output Enables (\overline{OEn}) are common to all flip–flops within the respective byte. The flip–flops will store the state of individual D inputs that meet the setup and hold time requirements on the LOW–to–HIGH Clock (CP) transition. With the \overline{OE} LOW, the contents of the flip–flops are available at the outputs. When the \overline{OE} is HIGH, the outputs go to the high impedance state. The \overline{OE} input level does not affect the operation of the flip–flops.

- Designed for Low Voltage Operation: $V_{CC} = 1.65-3.6 \text{ V}$
- 3.6 V Tolerant Inputs and Outputs
- High Speed Operation: 3.4 ns max for 3.0 to 3.6 V
 4.8 ns max for 2.3 to 2.7 V
 9.6 ns max for 1.65 to 1.95 V
- Static Drive: ±12 mA Drive at 3.0 V ±8 mA Drive at 2.3 V ±3 mA Drive at 1.65 V
- Supports Live Insertion and Withdrawal
- I_{OFF} Specification Guarantees High Impedance When $V_{CC} = 0$ V
- Near Zero Static Supply Current in All Three Logic States (20 μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds ±300mA @ 125°C
- ESD Performance: Human Body Model >2000 V; Machine Model >200 V



ON Semiconductor

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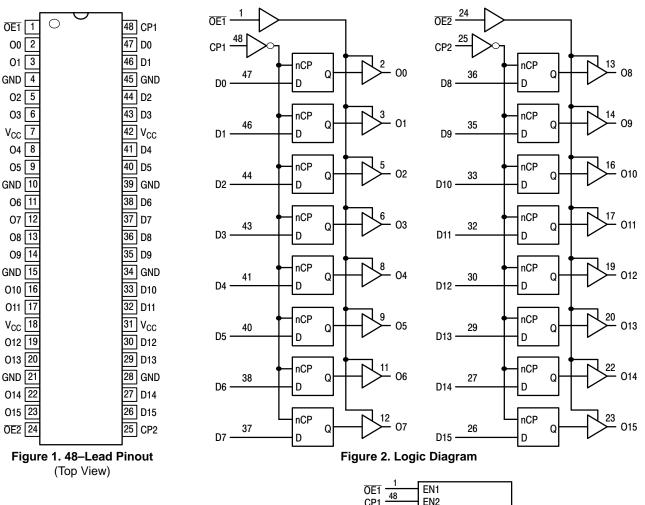


YVL = VValer LoYY = Year

WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
74VCX162374DT	TSSOP	39 / Rail
74VCX162374DTR	TSSOP	2500 / Reel



PIN NAMES				
Pins	Function			
OEn CPn D0–D15 O0–O15	Output Enable Inputs Clock Pulse Inputs Inputs Outputs			

1				1
OE1	EN1			
CD1 40	EN2			
CP2 24	EN3			
0E2	EN4			
D0 47		1	1 🗸	$ \begin{array}{c c} 2 & 00 \\ 3 & 01 \\ 5 & 02 \\ 6 & 03 \\ 8 & 04 \\ 9 & 05 \\ 11 & 06 \\ \end{array} $
D1 46				3 01
4.4				3 5 02
D2 40				<u> </u>
D3 43		1	2 🗸	<u> </u>
D4 41				<u> </u>
				9 05
				<u>9</u> 05
$D_{0} = \frac{38}{37}$				<u> </u>
D0 D7 <u>37</u> 36		1	3 $ abla$	$\frac{11}{12}$ 06 12 07
D8 36		· ·	3 1	$\frac{12}{13}$ 07
D0-05				44 00
09	4			
D10 33				16 O10
		4		17 010
		1	4 $ abla$	10 011
	1			19 012
D13				20 012 20 013
D13 D14 27				
D14 D15				
D15-20	4			<u></u> 015
				1

	Inputs		Outputs	Inputs			Outputs
CP1	OE1	D0:7	O0:7	CP2	OE2	D8:15	O8:15
Ŷ	L	н	Н	1 1	L	Н	Н
Ŷ	L	L	L	↑	L	L	L
Х	L	Х	O0	Х	L	Х	O0
Х	Н	Х	Z	Х	Н	Х	Z

H = High Voltage Level; L = Low Voltage Level; Z = High Impedance State; \uparrow = Low–to–High Transition; X = High or Low Voltage Level and Transitions Are Acceptable, for I_{CC} reasons, DO NOT FLOAT Inputs. O0 = No Change.

ABSOLUTE MAXIMUM RATINGS*

Symbol	Parameter	Value	Condition	Unit
V _{CC}	DC Supply Voltage	-0.5 to +4.6		V
VI	DC Input Voltage	$-0.5 \le V_1 \le +4.6$		V
Vo	DC Output Voltage	$-0.5 \le V_0 \le +4.6$	Output in 3-State	V
		$-0.5 \leq V_O \leq V_{CC} + 0.5$	Note 1.; Outputs Active	V
I _{IK}	DC Input Diode Current	-50	V _I < GND	mA
I _{OK}	DC Output Diode Current	-50	V _O < GND	mA
		+50	$V_{O} > V_{CC}$	mA
IO	DC Output Source/Sink Current	±50		mA
I _{CC}	DC Supply Current Per Supply Pin	±100		mA
I _{GND}	DC Ground Current Per Ground Pin	±100		mA
T _{STG}	Storage Temperature Range	-65 to +150		°C

* Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied.

1. I_O absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Тур	Max	Unit
V _{CC}	Supply Voltage	Operating Data Retention Only	1.65 1.2	3.3 3.3	3.6 3.6	V
VI	Input Voltage		-0.3		3.6	V
V _O	Output Voltage	(Active State) (3–State)	0 0		V _{CC} 3.6	V
I _{OH}	HIGH Level Output Current, V _{CC} = 3.0V - 3.6V				-12	mA
I _{OL}	LOW Level Output Current, $V_{CC} = 3.0V - 3.6V$				12	mA
I _{OH}	HIGH Level Output Current, $V_{CC} = 2.3V - 2.7V$				-8	mA
I _{OL}	LOW Level Output Current, $V_{CC} = 2.3V - 2.7V$				8	mA
I _{OH}	HIGH Level Output Current, $V_{CC} = 1.65 - 1.95V$				-3	mA
I _{OL}	LOW Level Output Current, $V_{CC} = 1.65 - 1.95V$				3	mA
T _A	Operating Free–Air Temperature		-40		+85	°C
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate, V_{IN} from 0.8V to	2.0V, V _{CC} = 3.0V	0		10	ns/V

DC ELECTRICAL CHARACTERISTICS

			T _A = -40°0	l	
Symbol	Characteristic	Condition	Min	Max	Unit
VIH	HIGH Level Input Voltage (Note 2.)	$1.65V \le V_{CC} < 2.3V$	0.65 x V _{CC}		V
		$2.3V \le V_{CC} \le 2.7V$	1.6		
		$2.7V < V_{CC} \le 3.6V$	2.0		
V _{IL}	LOW Level Input Voltage (Note 2.)	$1.65V \le V_{CC} < 2.3V$		0.35 x V _{CC}	V
		$2.3V \le V_{CC} \le 2.7V$		0.7	
		$2.7V < V_{CC} \le 3.6V$		0.8	
V _{ОН}	HIGH Level Output Voltage	$1.65V \le V_{CC} \le 3.6V; I_{OH} = -100\mu A$	$V_{CC} - 0.2$		V
		V _{CC} = 1.65V; I _{OH} = -3mA	1.25		
		V _{CC} = 2.3V; I _{OH} = -4mA	2.0		
		V _{CC} = 2.3V; I _{OH} = -6mA	1.8		
		V _{CC} = 2.3V; I _{OH} = -8mA	1.7		
		V _{CC} = 2.7V; I _{OH} = -6mA	2.2		
		V _{CC} = 3.0V; I _{OH} = -8mA	2.4		
		V _{CC} = 3.0V; I _{OH} = -12mA	2.2		
V _{OL}	LOW Level Output Voltage	$1.65V \le V_{CC} \le 3.6V; I_{OL} = 100 \mu A$		0.2	V
		V _{CC} = 1.65V; I _{OL} = 3mA		0.3	
		$V_{CC} = 2.3V; I_{OL} = 6mA$		0.4	
		V _{CC} = 2.3V; I _{OL} = 8mA		0.6	
		$V_{CC} = 2.7V; I_{OL} = 6mA$		0.4	
		V _{CC} = 3.0V; I _{OL} = 8mA		0.55	
		V _{CC} = 3.0V; I _{OL} = 12mA		0.8	
l _l	Input Leakage Current	$1.65V \leq V_{CC} \leq 3.6V; 0V \leq V_I \leq 3.6V$		±5.0	μA
I _{OZ}	3–State Output Current	$\begin{array}{l} 1.65V \leq V_{CC} \leq 3.6V; \ 0V \leq V_O \leq 3.6V; \\ V_I = V_{IH} \ or \ V_{IL} \end{array} \label{eq:VCC}$		±10	μA
I _{OFF}	Power–Off Leakage Current	$V_{CC} = 0V; V_{I} \text{ or } V_{O} = 3.6V$		10	μA
I _{CC}	Quiescent Supply Current (Note 3.)	$1.65V \leq V_{CC} \leq 3.6V; \ V_{I}$ = GND or V_{CC}		20	μA
		$1.65V \le V_{CC} \le 3.6V; \ 3.6V \le V_I, \ V_O \le 3.6V$		±20	μA
ΔI_{CC}	Increase in I _{CC} per Input	$2.7V < V_{CC} \le 3.6V; V_{IH} = V_{CC} - 0.6V$	1	750	μA

2. These values of V_I are used to test DC electrical characteristics only. 3. Outputs disabled or 3–state only.

AC CHARACTERISTICS	(Note 4.; $t_R = t_F = 2.0$ ns; $C_L = 30$ pF; $R_L = 500\Omega$)
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			Limits						
			T _A = −40°C to +85°C						1
			V _{CC} = 3.0V to 3.6V		V _{CC} = 2.3	V _{CC} = 2.3V to 2.7V		V _{CC} = 1.65 to 1.95V	
Symbol	Parameter	Waveform	Min	Max	Min	Max	Min	Max	Unit
f _{max}	Clock Pulse Frequency	1	250		200		100		MHz
t _{PLH} t _{PHL}	Propagation Delay CP to On	1	0.8 0.8	3.4 3.4	1.0 1.0	4.8 4.8	1.5 1.5	9.6 9.6	ns
t _{PZH} t _{PZL}	Output Enable Time to High and Low Level	2	0.8 0.8	3.9 3.9	1.0 1.0	5.4 5.4	1.5 1.5	9.8 9.8	ns
t _{PHZ} t _{PLZ}	Output Disable Time From High and Low Level	2	0.8 0.8	4.0 4.0	1.0 1.0	4.4 4.4	1.5 1.5	7.9 7.9	ns
ts	Setup Time, High or Low Dn to CP	3	1.5		1.5		2.5		ns
t _h	Hold Time, High or Low Dn to CP	3	1.0		1.0		1.0		ns
tw	CP Pulse Width, High	3	1.5		1.5		4.0		ns
t _{OSHL} t _{OSLH}	Output-to-Output Skew (Note 5.)			0.5 0.5		0.5 0.5		0.75 0.75	ns

4. For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

 Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH–to–LOW (t_{OSHL}) or LOW–to–HIGH (t_{OSLH}); parameter guaranteed by design.

DYNAMIC SWITCHING CHARACTERISTICS

			T _A = +25°C	
Symbol	Characteristic	Condition	Тур	Unit
V _{OLP}	Dynamic LOW Peak Voltage	V_{CC} = 1.8V, C_L = 30pF, V_{IH} = V_{CC} , V_{IL} = 0V	0.15	V
	(Note 6.)	$V_{CC} = 2.5V, C_L = 30pF, V_{IH} = V_{CC}, V_{IL} = 0V$	0.25	
		$V_{CC} = 3.3 \text{V}, \text{C}_{\text{L}} = 30 \text{p}\text{F}, \text{V}_{\text{IH}} = \text{V}_{\text{CC}}, \text{V}_{\text{IL}} = 0 \text{V}$	0.35	
V _{OLV}	Dynamic LOW Valley Voltage	$V_{CC} = 1.8V, C_L = 30 \text{pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	-0.15	V
	(Note 6.)	$V_{CC} = 2.5V, C_L = 30pF, V_{IH} = V_{CC}, V_{IL} = 0V$	-0.25	
		$V_{CC} = 3.3 \text{V}, \text{C}_{\text{L}} = 30 \text{p}\text{F}, \text{V}_{\text{IH}} = \text{V}_{CC}, \text{V}_{\text{IL}} = 0 \text{V}$	-0.35	
V _{OHV}	Dynamic HIGH Valley Voltage	$V_{CC} = 1.8V, C_L = 30 p F, V_{IH} = V_{CC}, V_{IL} = 0 V$	1.55	V
	(Note 7.)	$V_{CC} = 2.5V, C_L = 30pF, V_{IH} = V_{CC}, V_{IL} = 0V$	2.05	
		V_{CC} = 3.3V, C_L = 30pF, V_{IH} = V_{CC} , V_{IL} = 0V	2.65	

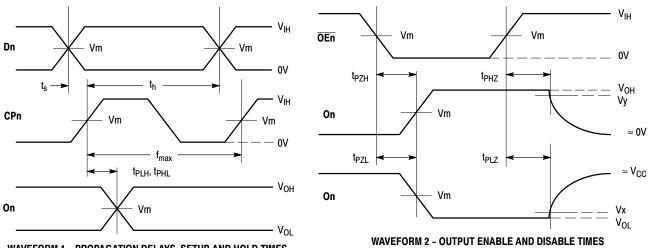
6. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

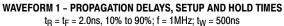
7. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the HIGH state.

CAPACITIVE CHARACTERISTICS

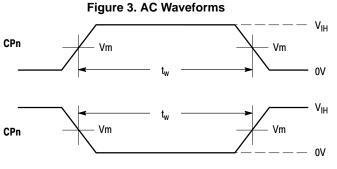
Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	Note 8.	6	pF
C _{OUT}	Output Capacitance	Note 8.	7	pF
C _{PD}	Power Dissipation Capacitance	Note 8., 10MHz	20	pF

8. V_{CC} = 1.8, 2.5 or 3.3V; V_I = 0V or V_{CC} .





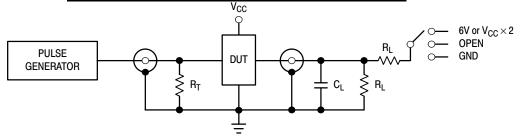
 $t_{R} = t_{F} = 2.0$ ns, 10% to 90%; f = 1MHz; $t_{W} = 500$ ns



WAVEFORM 3 - PULSE WIDTH t_{R} = t_{F} = 2.0ns (or fast as required) from 10% to 90%

Figure 4. AC Waveforms

	V _{CC}					
Symbol	3.3V ±0.3V	2.5V ±0.2V	1.8V ±0.15V			
V _{IH}	2.7V	V _{CC}	V _{CC}			
V _m	1.5V	V _{CC} /2	V _{CC} /2			
V _x	V _{OL} + 0.3V	V _{OL} + 0.15V	V _{OL} + 0.15V			
Vy	V _{OH} – 0.3V	V _{OH} – 0.15V	V _{OH} – 0.15V			

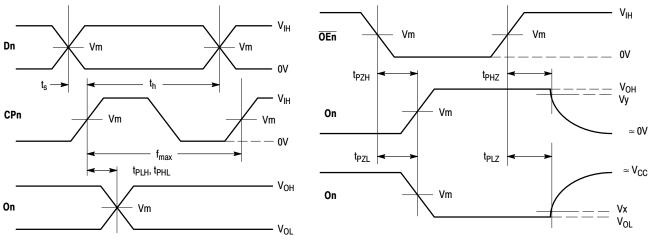


TEST	SWITCH
t _{PLH} , t _{PHL}	Open
t _{PZL} , t _{PLZ}	6V at V _{CC} = 3.3 ± 0.3 V; V _{CC} × 2 at V _{CC} = 2.5 ± 0.2 V; 1.8 V ± 0.15 V
t _{PZH} , t _{PHZ}	GND

C_L = 30pF or equivalent (Includes jig and probe capacitance)

 $R_{L} = 500\Omega$ or equivalent

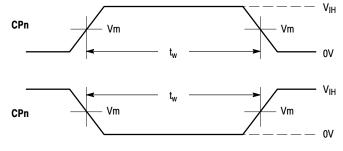
 $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω) Figure 5. Test Circuit

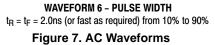




WAVEFORM 5 - OUTPUT ENABLE AND DISABLE TIMES $t_R = t_F = 2.0ns, 10\%$ to 90%; f = 1MHz; $t_W = 500ns$

Figure 6. AC Waveforms



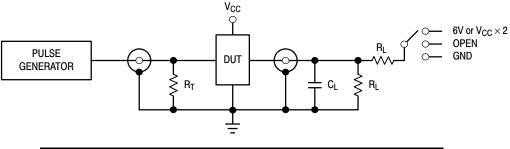


	V _{CC}		
Symbol	3.3V ±0.3V	2.7V	
V _{IH}	2.7V	2.7V	
V _m	1.5V	1.5V	
V _x	V _{OL} + 0.3V	V _{OL} + 0.3V	
Vy	V _{OH} – 0.3V	V _{OH} – 0.3V	

AC CHARACTERISTICS ($t_R = t_F = 2.0ns$; $C_L = 50pF$; $R_L = 500\Omega$)

			Limits T _A = -40°C to +85°C				
			V _{CC} = 3.0V to 3.6V		V _{CC} = 2.7V		1
Symbol	Parameter	Waveform	Min	Max	Min	Max	Unit
f _{max}	Clock Pulse Frequency	4	150		150		MHz
t _{PLH} t _{PHL}	Propagation Delay CP to On	4	1.0 1.0	4.6 4.6		5.4 5.4	ns
t _{PZH} t _{PZL}	Output Enable Time to High and Low Level	5	1.0 1.0	5.2 5.2		6.4 6.4	ns
t _{PHZ} t _{PLZ}	Output Disable Time From High and Low Level	5	1.0 1.0	4.5 4.5		5.0 5.0	ns
t _{OSHL} t _{OSLH}	Output-to-Output Skew (Note 9.)			0.5 0.5		0.5 0.5	ns

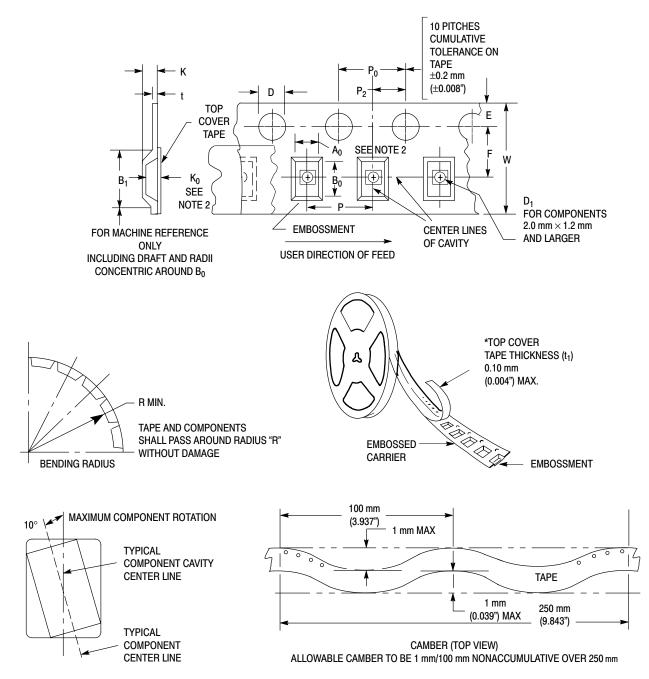
 Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH–to–LOW (t_{OSHL}) or LOW–to–HIGH (t_{OSLH}); parameter guaranteed by design.



TEST	SWITCH
t _{PLH} , t _{PHL}	Open
t _{PZL} , t _{PLZ}	6V at V _{CC} = 3.3 ±0.3V; V _{CC} × 2 at V _{CC} = 2.5 ±0.2V; 1.8V ±0.15V
t _{PZH} , t _{PHZ}	GND

 $\begin{array}{l} C_L = 50 pF \mbox{ or equivalent (Includes jig and probe capacitance)} \\ R_L = 500 \Omega \mbox{ or equivalent } \\ R_T = Z_{OUT} \mbox{ of pulse generator (typically 50 \Omega)} \end{array}$

Figure 8. Test Circuit





Tape Size	B ₁ Max	D	D ₁	E	F	к	Р	P ₀	P ₂	R	т	w
24mm	20.1mm (0.791")	1.5 + 0.1mm -0.0 (0.059 +0.004" -0.0)	1.5mm Min (0.060")	1.75 ±0.1 mm (0.069 ±0.004")	11.5 ±0.10 mm (0.453 ±0.004")	11.9 mm Max (0.468")	16.0 ±0.1 mm (0.63 ±0.004")	4.0 ±0.1 mm (0.157 ±0.004")	2.0 ±0.1 mm (0.079 ±0.004")	30 mm (1.18")	0.6 mm (0.024")	24.3 mm (0.957")

EMBOSSED CARRIER DIMENSIONS (See Notes 1 and 2)

1. Metric Dimensions Govern-English are in parentheses for reference only.

 A₀, B₀, and K₀ are determined by component size. The clearance between the components and the cavity must be within 0.05 mm min to 0.50 mm max. The component cannot rotate more than 10° within the determined cavity

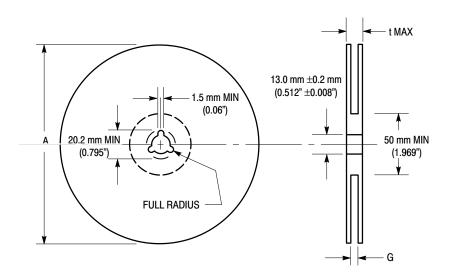
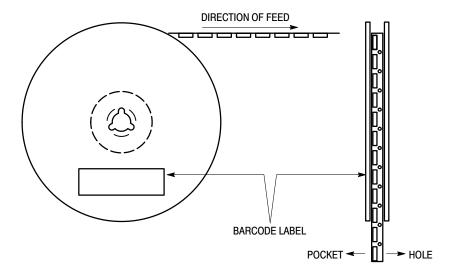


Figure 10. Reel Dimensions

REEL DIMENSIONS

Tape Size	A Max	G	t Max
24 mm	360 mm	24.4 mm + 2.0 mm, -0.0	30.4 mm
	(14.173")	(0.961" + 0.078", -0.00)	(1.197")





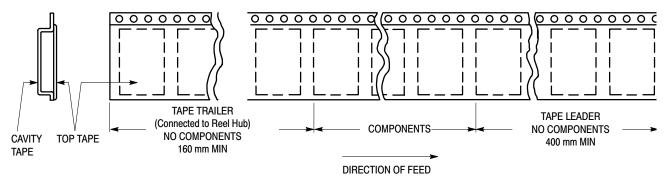
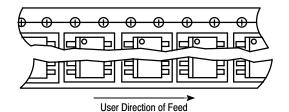
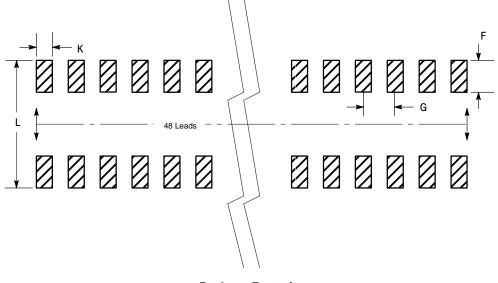


Figure 12. Tape Ends for Finished Goods



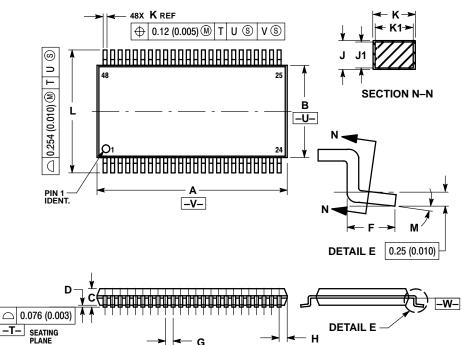




Package Footprint

PACKAGE DIMENSIONS

TSSOP DT SUFFIX CASE 1201-01 ISSUE A



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS
- SHALL NOT EXCEED 0.15 (0.006) PER SIDE. DIMENSION K DOES NOT INCLUDE DAMBAR 4
- PROTRUSION R DOES NOT INCLODE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
- TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY. DIMENSIONS A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	12.40	12.60	0.488	0.496	
В	6.00	6.20	0.236	0.244	
C		1.10		0.043	
D	0.05	0.15	0.002	0.006	
F	0.50	0.75	0.020	0.030	
G	0.50	BSC	0.0197 BSC		
н	0.37		0.015		
J	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
K	0.17	0.27	0.007	0.011	
K1	0.17	0.23	0.007	0.009	
L	7.95	8.25	0.313	0.325	
М	0 °	8 °	0 °	8 °	

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